# NSN 5961-01-073-6651

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#### Inclosure Material:

Metal

**Overall Length:** 

1.195 inches

### Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-61

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Burn in and hermetically sealed case

#### **Overall Width Across Flats:**

0.677 inches

#### Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

12.00 amperes source cutoff current and 6.00 amperes source cutoff current

#### Power Rating Per Characteristic:

80.0 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

200.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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